



US 20240213288A1

(19) **United States**

(12) **Patent Application Publication**
YAMASHITA et al.

(10) **Pub. No.: US 2024/0213288 A1**

(43) **Pub. Date: Jun. 27, 2024**

(54) **LIGHT DETECTING DEVICE AND
ELECTRONIC DEVICE**

Publication Classification

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(51) **Int. Cl.**
H01L 27/146 (2006.01)

(52) **U.S. Cl.**
CPC .. H01L 27/14636 (2013.01); **H01L 27/14612**
(2013.01); **H01L 27/1463** (2013.01)

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(57) **ABSTRACT**

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Alight detecting device includes a semiconductor layer having a first surface and a second surface located on opposite sides to each other in a thickness direction, and a photoelectric conversion cell provided in the semiconductor layer and partitioned by a first isolation region. The photoelectric conversion cell includes a first photoelectric conversion region adjacent to a second photoelectric conversion region in plan view and each having a photoelectric conversion unit and a transfer transistor, a second isolation region arranged between the first photoelectric conversion region and the second photoelectric conversion region in plan view and extending in a thickness direction of the semiconductor layer, and an element formation region partitioned on the first surface side of the semiconductor layer by a third isolation region and provided with a pixel transistor. The element formation region extends over the first and second photoelectric conversion regions in plan view.

(21) Appl. No.: **18/594,103**

(22) Filed: **Mar. 4, 2024**

Related U.S. Application Data

(62) Division of application No. 18/259,947, filed on Jun. 29, 2023, filed as application No. PCT/JP2022/010411 on Mar. 9, 2022.

(30) **Foreign Application Priority Data**

Mar. 31, 2021 (JP) 2021-062418

